

## Pin Descriptions

| Pin# | Pin Name         | Pin Type |          | Pin Description                                       |
|------|------------------|----------|----------|-------------------------------------------------------|
| 1    | V <sub>DDO</sub> | Power    |          | Output supply pin.                                    |
| 2    | V <sub>DD</sub>  | Power    |          | Positive supply pin.                                  |
| 3    | CLK              | Input    | Pulldown | LVCMOS / LVTTL clock input.                           |
| 4    | GND              | Power    |          | Power supply ground.                                  |
| 5    | Q0               | Output   |          | Single clock output. LVCMOS / LVTTL interface levels. |
| 6    | Q1               | Output   |          | Single clock output. LVCMOS / LVTTL interface levels. |
| 7    | Q2               | Output   |          | Single clock output. LVCMOS / LVTTL interface levels. |
| 8    | Q3               | Output   |          | Single clock output. LVCMOS / LVTTL interface levels. |

Note: *Pulldown* refers to internal input resistors. See Table 2, *Pin Characteristics*, for typical values.

## Pin Characteristics

| Symbol                | Parameter                                  | Test Conditions                             | Min. | Typical | Max. | Units |
|-----------------------|--------------------------------------------|---------------------------------------------|------|---------|------|-------|
| C <sub>IN</sub>       | Input Capacitance                          |                                             |      | 4       |      | pF    |
| C <sub>PD</sub>       | Power Dissipation Capacitance (per output) | V <sub>DD</sub> , V <sub>DDO</sub> = 3.465V |      |         | 15   | pF    |
| R <sub>PULLDOWN</sub> | Input Pulldown Resistor                    |                                             |      | 51      |      | kΩ    |
| R <sub>OUT</sub>      | Output Impedance                           | V <sub>DD</sub> , V <sub>DDO</sub> >2.5V    | 5    | 7       | 12   | Ω     |

## Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

|                                          |                           |
|------------------------------------------|---------------------------|
| Supply Voltage, $V_{DD}$                 | 4.6V                      |
| Inputs, $V_I$                            | -0.5V to $V_{DD} + 0.5V$  |
| Output, $V_O$                            | -0.5V to $V_{DDO} + 0.5V$ |
| Package Thermal Impedance, $\theta_{JA}$ | 112.7°C/W (0 lfpm)        |
| Storage Temperature, $T_{STG}$           | -65°C to 150°C            |

Note:

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the DC Characteristics or AC Characteristics is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

**Table 3A. Power Supply DC Characteristics,  $T_A = 0^\circ\text{C}$  TO  $70^\circ\text{C}$**

| Symbol    | Parameter                   | Conditions     | Min.  | Typ. | Max.  | Units |
|-----------|-----------------------------|----------------|-------|------|-------|-------|
| VDD       | Core Supply Voltage         | 3.3V Operation | 3.135 | 3.3  | 3.465 | V     |
| VDDO      | Output Power Supply Voltage | 3.3V Supply    | 3.135 | 3.3  | 3.465 | V     |
|           |                             | 2.5V Supply    | 2.375 | 2.5  | 2.625 |       |
| $I_{DD}$  | Power Supply Current        |                |       |      | 22    | mA    |
| $I_{DDO}$ | Output Supply Current       | 25MHz          |       |      | 7     | mA    |
|           |                             | 200MHz         |       |      | 45    | mA    |

**LVCMOS / LVTTL DC CHARACTERISTICS,  $T_A = 0^\circ\text{C}$  to  $70^\circ\text{C}$** 

| Symbol   | Parameter           | Conditions                  | Min.                          | Typ. | Max.    | Units         |
|----------|---------------------|-----------------------------|-------------------------------|------|---------|---------------|
| $V_{IH}$ | Input High Voltage  | VDD = 3.3V                  | 2.3                           |      | VDD+0.3 | V             |
|          |                     | VDD = 2.5V                  | 1.7                           |      | VDD+0.3 |               |
| $V_{IL}$ | Input Low Voltage   | VDD = 3.3V                  | -0.3                          |      | 0.8     | V             |
|          |                     | VDD = 2.5V                  | -0.3                          |      | 0.8     |               |
| $I_{IH}$ | Input High Current  | VDD = $V_{IN}$ = 3.465V     |                               |      | 150     | $\mu\text{A}$ |
| $I_{IL}$ | Input Low Current   | VDD = 3.465V, $V_{IN}$ = 0V | -5                            |      |         | $\mu\text{A}$ |
| $V_{OH}$ | Output High Voltage | VDDO = 3.3V                 | 50 $\Omega$ to VDDO /2        | 2.6  |         | V             |
|          |                     |                             | $I_{OH}$ = -100 $\mu\text{A}$ | 2.9  |         | V             |
|          |                     | VDDO = 2.5V                 | 50 $\Omega$ to VDDO /2        | 1.8  |         | V             |
|          |                     |                             | $I_{OH}$ = -100 $\mu\text{A}$ | 2.2  |         | V             |
| $V_{OL}$ | Output High Voltage | VDDO = 3.3V                 | 50 $\Omega$ to VDDO /2        |      | 0.5     | V             |
|          |                     |                             | $I_{OH}$ = -100 $\mu\text{A}$ |      | 0.2     | V             |
|          |                     | VDDO = 2.5V                 | 50 $\Omega$ to VDDO /2        |      | 0.5     | V             |
|          |                     |                             | $I_{OH}$ = -100 $\mu\text{A}$ |      | 0.2     | V             |

**AC CHARACTERISTICS**,  $V_{DD} = 3.3V \pm 5\%$ ,  $T_A = 0^\circ C$  to  $70^\circ C$

| Symbol       | Parameter                                 | Conditions                               | Min. | Typ. | Max. | Units |
|--------------|-------------------------------------------|------------------------------------------|------|------|------|-------|
| $f_{MAX}$    | Output Frequency                          | $V_{DDO} = 3.3V$                         |      |      | 200  | MHz   |
|              |                                           | $V_{DDO} = 2.5V$                         |      |      | 200  |       |
| $t_{p_{LH}}$ | Propagation Delay, Low-to-High;<br>NOTE 1 | $V_{DDO} = 3.3V, f \leq 200MHz$          | 1.9  | 2.35 | 2.8  | ns    |
|              |                                           | $V_{DDO} = 2.5V, f \leq 200MHz$          | 2.3  |      | 3.3  |       |
| $tsk(o)$     | Output Skew; NOTE 2                       |                                          |      | 25   | 100  | ps    |
| $tsk(pp)$    | Part-to-Part Skew; NOTE 3                 |                                          |      | 250  | 500  | ps    |
| $t_R$        | Output Rise Time NOTE 4                   | $V_{DDO} = 3.3V$                         | 280  |      | 800  | ps    |
|              |                                           | $V_{DDO} = 2.5V$                         | 280  |      | 850  |       |
| $t_F$        | Output Fall Time NOTE 4                   | $V_{DDO} = 3.3V$                         | 280  |      | 800  | ps    |
|              |                                           | $V_{DDO} = 2.5V$                         | 280  |      | 850  |       |
| odc          | Output Duty Cycle                         | $V_{DDO} = 3.3V, f \leq 133MHz$          | 45   |      | 55   | %     |
|              |                                           | $V_{DDO} = 3.3V, 133MHz < f \leq 200MHz$ | 40   |      | 60   | %     |
|              |                                           | $V_{DDO} = 2.5V, f \leq 133MHz$          | 45   |      | 55   | %     |
|              |                                           | $V_{DDO} = 2.5V, 133MHz < f \leq 200MHz$ | 40   |      | 60   | %     |
| $t_{jit}$    | Additive RMS Jitter                       | 156.25MHz (@12kHz to 20MHz)              |      | 0.06 |      | ps    |
|              |                                           | 125MHz (@12kHz to 20MHz)                 |      | 0.04 |      | ps    |

Parameters measured at  $f_{MAX}$  unless otherwise noted.

NOTE 1: Measured from  $V_{DD} / 2$  of the input to  $V_{DDO} / 2$  of the output.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at  $V_{DDO} / 2$ .

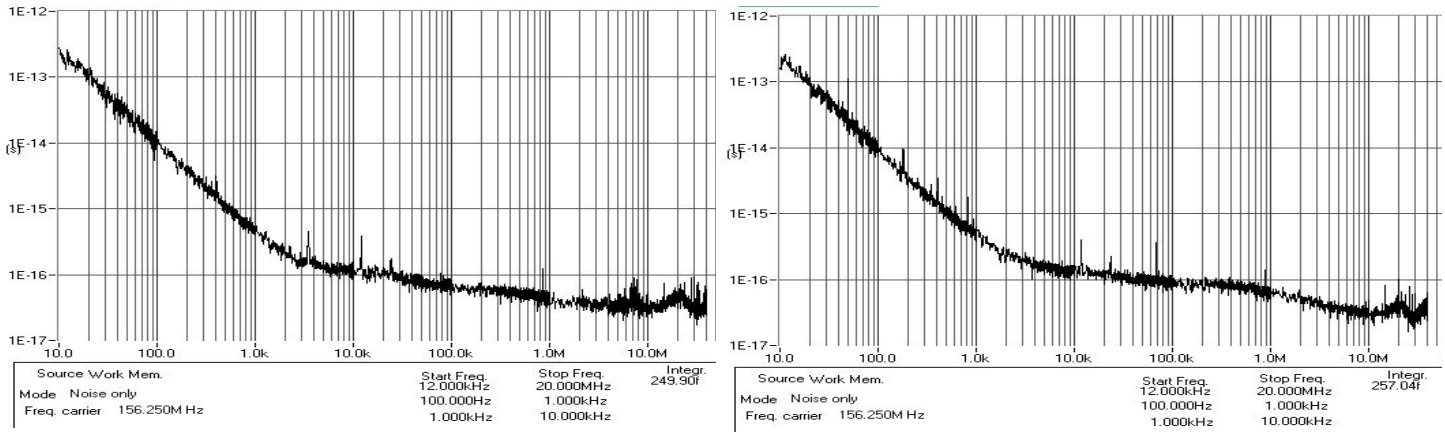
NOTE 3: Defined as skew between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at  $V_{DDO} / 2$ .

NOTE 4: Defined from 20% to 80%

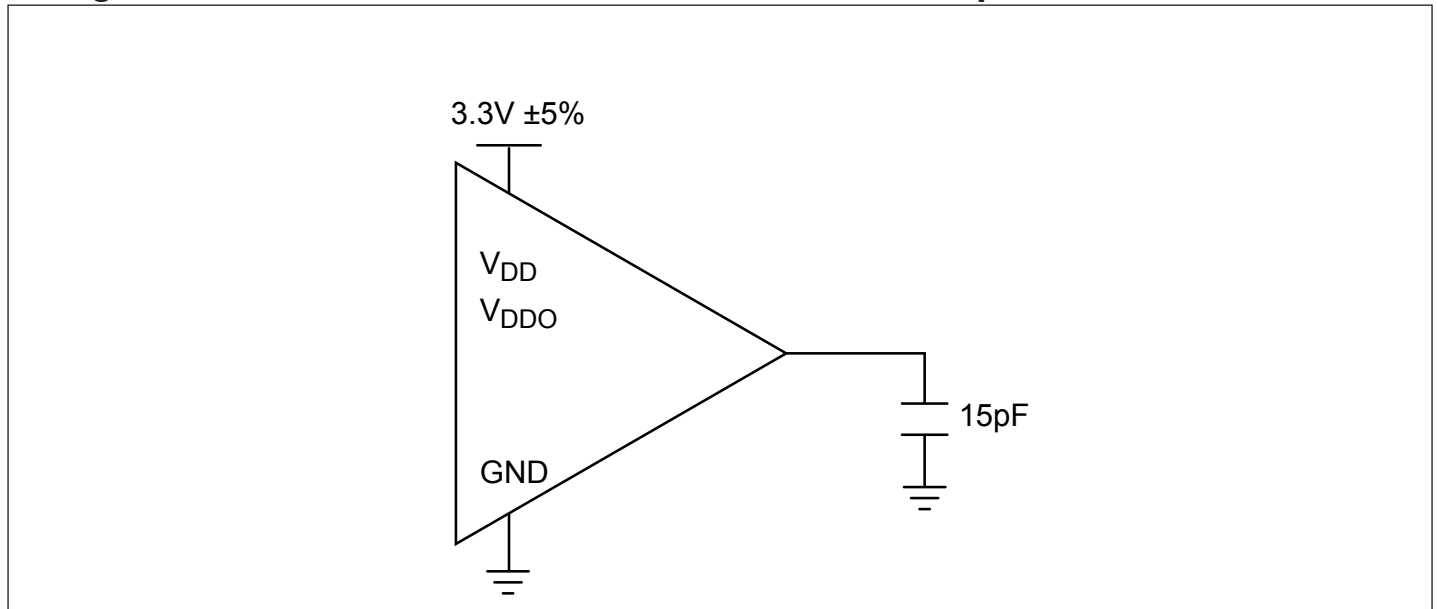
### Phase Noise and Additive Jitter

Output phase noise (Right plot) vs Input Phase noise (Left plot)

Additive jitter is calculated at ~60.2fs RMS (12kHz to 20MHz). Additive jitter =  $\sqrt{(\text{Output jitter}^2 - \text{Input jitter}^2)}$

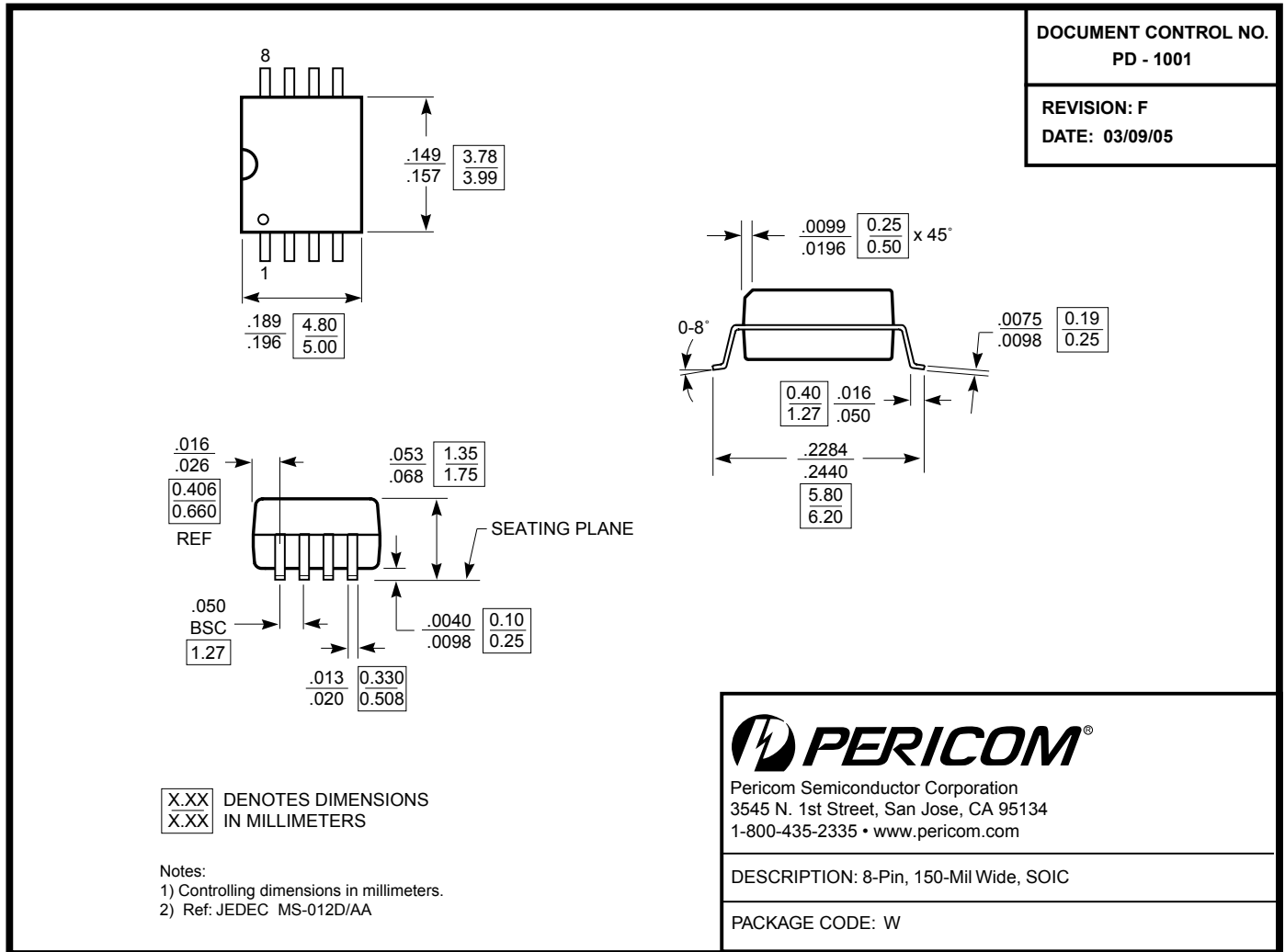


### Configuration Test Load Board Termination for LVCMOS Outputs



### Thermal Information

| Symbol        | Description                            | Condition |          |
|---------------|----------------------------------------|-----------|----------|
| $\Theta_{JA}$ | Junction-to-ambient thermal resistance | Still air | 157 °C/W |
| $\Theta_{JC}$ | Junction-to-case thermal resistance    |           | 42 °C/W  |



**Note:**

- For latest package info, please check: <http://www.pericom.com/products/packaging/mechanicals.php>

**Ordering Information<sup>(1-3)</sup>**

| Ordering Code    | Package Code | Package Description          |
|------------------|--------------|------------------------------|
| PI6C49X0204B-AWE | W            | 8-pin, Pb-free & Green, SOIC |

**Notes:**

- Thermal characteristics can be found on the company web site at [www.pericom.com/packaging/](http://www.pericom.com/packaging/)
- E = Pb-free and Green
- Adding an X suffix = Tape/Reel